



Features:

- RoHS Compliant
- 10 Watts
- Low Cost
- DC 6.0GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Outline Drawing

Surface Mount Attenuator 10 Watts, 20dB

The XRA10AA20SES is a high performance Aluminum Nitride (AIN) chip attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). It is designed particularly for LTE and 5G wireless commination frequency bands. The high power handling makes the part ideal for interstage matching, directional couplers, and for use in isolators. The attenuator is also RoHS compliant!

General Specifications

Resistive Element Thick film

Substrate AIN Ceramic

Terminal Finish Matte Tin over Nickel Barrier

Operating
Temperature
-55 to +150°C (see de-rating chart)

Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. **All dimensions in inches.**

Electrical Specifications

 Attenuation Value:
 20dB ±1.0 dB

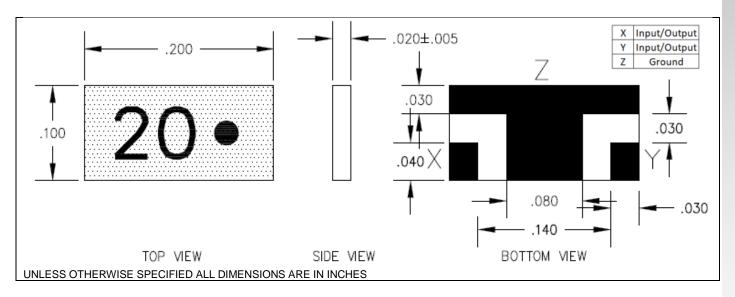
 Power:
 10 Watts

 Frequency Range:
 DC - 6.0GHz

 Input Return Loss:
 20dB DC - 5.0GHz

 18dB 5.0 - 6.0GHz

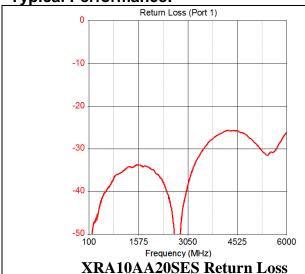
Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

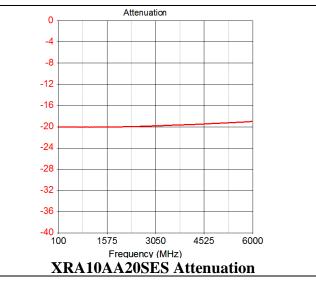




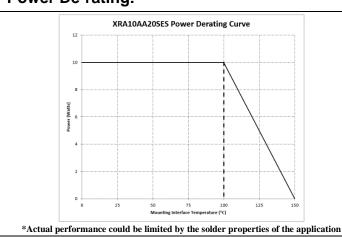


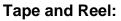
Typical Performance:

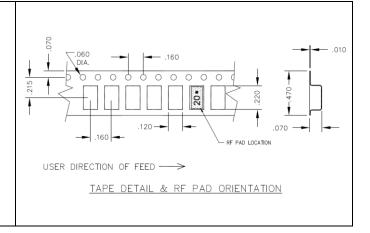




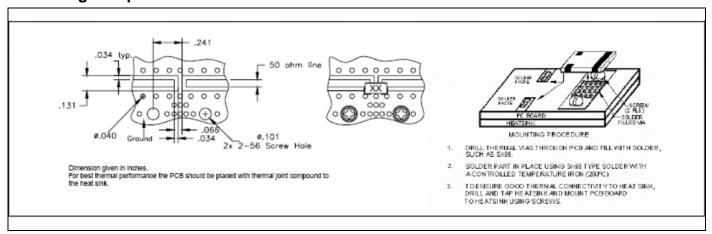
Power De-rating:







Mounting Footprint:



USA/Canada: Toll Free: Europe: (315) 432-8909 (800) 544-2414 +44 2392-232392

